NSN 5961-00-549-1962

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-549-1962

Inclosure Material:

Metal

Overall Length:

0.200 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.210 inches

Internal Configuration:

Field effect

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

20.0 drain to source voltage and 20.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source and 30.0

breakdown voltage, drain-to-source, with all other terminals short-circuited to source

Current Rating Per Characteristic:

10.00 milliamperes gate current

Power Rating Per Characteristic:

300.0 milliwatts collector power dissipation

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0